NSN 5961-00-137-7306

Thyristor Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-137-7306 **Inclosure Material:** Metal **Overall Length:** 2.560 inches **Overall Diameter:** 1.031 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 off-state voltage, dc **Current Rating Per Characteristic:** 150.00 milliamperes forward current, total rms preset **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 120.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

NSN 5961-00-137-7306

Thyristor Semiconductor Device - Page 2 of 2



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